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- 3-State Outputs Interface Directly With System Bus
- Provide Bus Interface From Multiple Sources in High-Performance Systems
- Package Options Include Plastic Small-Outline (D) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

These data selectors/multiplexers are designed to multiplex signals from 4-bit data sources to 4-output data lines in bus-organized systems. The 3-state outputs do not load the data lines when the output-enable (\overline{OE}) input is at a high logic level.

The SN54ALS257A and SN54ALS258A are characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ALS257A, SN74ALS258A, SN74AS257, and SN74AS258 are characterized for operation from 0°C to 70°C.

SN54ALS257A, SN54ALS258A J PACKAGE
SN74ALS257A, SN74ALS258A, SN74AS257,
SN74AS258 D OR N PACKAGE
(TOP VIEW)

A/B [1A [1B [1Y [2 3 4	σ	14 13] V _{CC}] OE] 4A] 4B
2A [2B [2Y [GND [5 6 7 8		12 11 10 9] 4Y] 3A] 3B] 3Y

SN54ALS257A, SN54ALS258A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

	INP	JTS		OUTF	Y TU				
	-	DA	TA	SN54ALS257A	SN54ALS258A				
OE	A/B	Α	В	SN74ALS257A SN74AS257	SN74ALS258A SN74AS258				
Н	Х	Х	Х	Z	Z				
L	L	L	Х	L	н				
L	L	н	Х	н	L				
L	Н	Х	L	L	н				
L	Н	Х	Н	н	L				

FUNCTION TABLE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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logic symbols[†]



 † These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, and N packages.

logic diagrams (positive logic)





Pin numbers shown are for the D, J, and N packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC}	7 V
Input voltage, V	
Voltage applied to a disabled 3-state output	5.5 V
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 1): D package	1.3 W
N package	1.1 W
Operating free-air temperature range, TA: SN54ALS257A, SN54ALS258A	-55°C to 125°C
SN74ALS257A, SN74ALS258A	0°C to 70°C
Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions

			54ALS25 54ALS25		SN74ALS257A SN74ALS258A			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.7			0.8	V
ЮН	High-level output current			-1			-2.6	mA
IOL	Low-level output current			12			24	mA
TA	Operating free-air temperature	-55		125	0		70	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CON	EST CONDITIONS		4ALS257 4ALS258		-	4ALS257 4ALS258		UNIT
				MIN	TYP†	MAX	MIN	TYP [†]	MAX	
VIK		V _{CC} = 4.5 V,	lı = -18 mA			-1.5			-1.5	V
		$V_{CC} = 4.5 V \text{ to } 5.5 V,$	I _{OH} = -0.4 mA	V _{CC} -2			V _{CC} –2			
VOH		V _{CC} = 4.5 V	I _{OH} = -1 mA	2.4	3.3					V
		VCC = 4.5 V	I _{OH} = -2.6 mA				2.4	3.2		
Vau		V _{CC} = 4.5 V	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
VOH		VCC = 4.5 V	I _{OL} = 24 mA					0.35	0.5	v
IOZH		V _{CC} = 5.5 V,	V _O = 2.7 V			20			20	μΑ
I _{OZL}		V _{CC} = 5.5 V,	$V_{O} = 0.4 V$			-20			-20	μΑ
Ц		V _{CC} = 5.5 V,	$V_{I} = 7 V$			0.1			0.1	mA
Ι _{ΙΗ}		V _{CC} = 5.5 V,	V _I = 2.7 V			20			20	μΑ
۱ _{IL}		V _{CC} = 5.5 V,	$V_I = 0.4 V$			-0.1			-0.1	mA
10‡		V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
			Outputs high		3	8		3	6	
	SN54ALS257A, SN74ALS257A	V _{CC} = 5.5 V	Outputs low		8	12		8	12	
laa	ONT-FALCEOFA	Outputs disabled	9	14		9	14	mA		
ICC			Outputs high		2.5	5		2.5	4	mA
	SN54ALS258A, SN74ALS258A	V _{CC} = 5.5 V	Outputs low		7	11		7	11	
			Outputs disabled		8	13		8	13	

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡]The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

switching characteristics (see Figure 1)

PARAMETER	METER FROM TO (INPUT) (OUTPUT)		CL : R1 : R2 :	c = 4.5 V = 50 pF, = 500 Ω, = 500 Ω, = MIN to			UNIT
			SN54AL	S257A	SN74AL	S257A	
			MIN	MAX	MIN	MAX	
^t PLH	A or B	Any Y	2	12	2	10	ns
^t PHL		Ally I	2	14	2	12	115
^t PLH	Ā/B	Δον Χ	4	21	6	18	20
^t PHL	A/B	Any Y	6	25	6	22	ns
^t PZH		Any Y	3	20	4	16	ns
^t PZL	ŌĒ		4	22	5	18	115
^t PHZ	OE	Δην.Υ	2	12	2	10	200
^t PLZ	UE	Any Y	2	35	4	15	ns

§ For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.



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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CL R1 R2	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T _A = MIN to MAX [†]				
			SN54AL	S258A	SN74AL	S258A		
			MIN	MAX	MIN	MAX		
^t PLH	A or B	Any Y	1	12	2	8	ns	
^t PHL	AUR	Ally I	2	9	2	7	115	
^t PLH	Ā/B	Any Y	4	28	5	25	20	
^t PHL	А/В		5	25	6	20	ns	
^t PZH		Anu V	3	20	4	18		
^t PZL	OE	Any Y	5	21	5	18	ns	
^t PHZ	OE	Anu V	2	12	2	10		
^t PLZ		Any Y	3	37	4	18	ns	

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Input voltage, V _I	
Voltage applied to a disabled 3-state output	5.5 V
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 1): D package	1.3 W
N package	1.1 W
Operating free-air temperature range, T _A : SN74AS257, SN74AS258	0°C to 70°C
Storage temperature range, T _{stg}	

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions

		SN74AS257 SN74AS258			UNIT
		MIN	NOM	MAX	
Vcc	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ЮН	High-level output current			-15	mA
IOL	Low-level output current			48	mA
ТА	Operating free-air temperature	0		70	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TES	TEST CONDITIONS		74AS25 74AS258		UNIT	
				MIN	түр†	MAX		
VIK		V _{CC} = 4.5 V,	lı = –18 mA			-1.2	V	
Varia		V _{CC} = 4.5 V to 5.5 V,	I _{OH} = -2 mA	V _{CC} -2			V	
Vон		$V_{CC} = 4.5 V,$	I _{OH} = -15 mA	2.4	3.2		V	
VOL		$V_{CC} = 4.5 V,$	I _{OL} = 48 mA		0.35	0.5	AX 1.2 V 1.2 V 0.5 V 50 μA -50 μA 0.1 mA 0.2 μA 0.1 mA 0.2 μA 112 mA 9.7	
IOZH		V _{CC} = 5.5 V,	V _O = 2.7 V			50	μA	
IOZL		V _{CC} = 5.5 V,	$V_{O} = 0.4 V$			-50	μΑ	
1.	A, B, or OE		<u>)/. 7)/</u>			0.1		
łı	Ā/B	V _{CC} = 5.5 V,	V _I = 7 V			0.2	0.2 mA	
	A, B, or OE	V _{CC} = 5.5 V,	<u>)/ 07)/</u>			20		
ΙΗ	Ā/B		V ₁ = 2.7 V			40	μΑ	
	A, B, or OE		N 0.4N			-0.5		
ŧι∟	Ā/B	V _{CC} = 5.5 V,	V _I = 0.4 V			-1	MA	
10‡	•	V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	mA	
			Outputs high		12.1	19.7		
	SN74AS257	$V_{CC} = 5.5 V$	Outputs low		19	30.6		
100			Outputs disabled		19.7	31.9	mA	
ICC			Outputs high		8.4	13.5	mA	
	SN74AS258	V _{CC} = 5.5 V	Outputs low		15.2	24.6		
			Outputs disabled		15.5	25.2		

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[‡] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.



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switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5 V f$ $C_{L} = 50 pF,$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_{A} = MIN to M$ SN74AS	MAX† 257	UNIT
			MIN	MAX	
^t PLH	A or B	Any Y	1	5.5	ns
^t PHL			1	6	115
^t PLH	Ā/B	Any Y	2	11	
^t PHL	A/B	Ally f	2	10	ns
^t PZH			2	7.5	
tPZL	OE	Any Y	2	9.5	ns
^t PHZ	ŌĒ		1.5	6.5	
^t PLZ	UE	Any Y	2	7	ns

switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5 V \text{ to } 5.5 V,$ $C_{L} = 50 \text{ pF},$ $R1 = 500 \Omega,$ $R2 = 500 \Omega,$ $T_{A} = \text{MIN to MAX}^{\dagger}$ SN74AS258		UNIT
			MIN	MAX	
t _{PLH}	A or B	Any Y	1	5	ns
^t PHL			1	4	
^t PLH	Ā/B	Any Y	2	9.5	ns
^t PHL			2	10	
^t PZH	ŌĒ	Anvi V	2	8	ns
tPZL		Any Y	2	10	
^t PHZ	ŌĒ	Any Y	1.5	6	ns
^t PLZ			2	6.5	

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.



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NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR \leq 1 MHz, t_f = t_f = 2 ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms



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